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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

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Details	
Product Status	Active
Core Processor	dsPIC
Core Size	16-Bit
Speed	60 MIPs
Connectivity	CANbus, I ² C, IrDA, LINbus, QEI, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, Motor Control PWM, POR, PWM, WDT
Number of I/O	35
Program Memory Size	32KB (10.7K x 24)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2K x 16
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 9x10b/12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	48-UFQFN Exposed Pad
Supplier Device Package	48-UQFN (6x6)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/dspic33ep32mc504-e-mv

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

TABLE 2: dsPIC33EPXXXMC20X/50X and PIC24EPXXXMC20X MOTOR CONTROL FAMILIES

FA	MIL	ES											_	_	_	_			_	_	
	()	es)				Rei	mappa	ble P	eriphe	erals					-						
Device	Page Erase Size (Instructions)	Program Flash Memory (Kbytes)	RAM (Kbytes)	16-Bit/32-Bit Timers	Input Capture	Output Compare	Motor Control PWM ⁽⁴⁾ (Channels)	Quadrature Encoder Interface	UART	SPI ⁽²⁾	ECAN™ Technology	External Interrupts ⁽³⁾	I²C™	CRC Generator	10-Bit/12-Bit ADC (Channels)	Op Amps/Comparators	CTMU	PTG	I/O Pins	Pins	Packages
PIC24EP32MC202	512	32	4																		
PIC24EP64MC202	1024	64	8																		SPDIP,
PIC24EP128MC202	1024	128	16	5	4	4	6	1	2	2	_	3	2	1	6	2/3(1)	Yes	Yes	21	28	SOIC, SSOP ⁽⁵⁾ ,
PIC24EP256MC202	1024	256	32																		QFN-S
PIC24EP512MC202	1024	512	48																		
PIC24EP32MC203	512	32	4	-			<u> </u>	,	6	6		<u> </u>	6		_		v	~	0-) (T) A
PIC24EP64MC203	1024	64	8	5	4	4	6	1	2	2	_	3	2	1	8	3/4	Yes	Yes	25	36	VTLA
PIC24EP32MC204	512	32	4															1			
PIC24EP64MC204	1024	64	8																		VTLA ⁽⁵⁾ ,
PIC24EP128MC204	1024	128	16	5	4	4	6	1	2	2	_	3	2	1	9	3/4	Yes	Yes	35	44/ 48	TQFP, QFN,
PIC24EP256MC204	1024	256	32																	40	UQFN
PIC24EP512MC204	1024	512	48																		
PIC24EP64MC206	1024	64	8																		
PIC24EP128MC206	1024	128	16	F	4	4	6	4	2	2		2	2	1	10	2/4	Vaa	Vaa	50	64	TQFP,
PIC24EP256MC206	1024	256	32	5	4	4	6	1	2	2	_	3	2	1	16	3/4	Yes	Yes	53	64	QFN
PIC24EP512MC206	1024	512	48																		
dsPIC33EP32MC202	512	32	4																		
dsPIC33EP64MC202	1024	64	8																		SPDIP,
dsPIC33EP128MC202	1024	128	16	5	4	4	6	1	2	2	_	3	2	1	6	2/3 (1)	Yes	Yes	21	28	SOIC, SSOP ⁽⁵⁾ ,
dsPIC33EP256MC202	1024	256	32																		QFN-S
dsPIC33EP512MC202	1024	512	48																		
dsPIC33EP32MC203	512	32	4	5	4	4	6	1	2	2		3	2	1	8	3/4	Yes	Yes	25	36	VTLA
dsPIC33EP64MC203	1024	64	8	э	4	4	0	-	2	2		ა	2	I	0	3/4	res	tes	25	30	VILA
dsPIC33EP32MC204	512	32	4																		
dsPIC33EP64MC204	1024	64	8																		VTLA ⁽⁵⁾ ,
dsPIC33EP128MC204	1024	128	16	5	4	4	6	1	2	2	—	3	2	1	9	3/4	Yes	Yes	35	44/ 48	TQFP, QFN,
dsPIC33EP256MC204	1024	256	32																		UQFN
dsPIC33EP512MC204	1024	512	48																		
dsPIC33EP64MC206	1024	64	8																		
dsPIC33EP128MC206	1024	128	16	5	4	4	6	1	2	2	_	3	2	1	16	3/4	Yes	Yes	53	64	TQFP,
dsPIC33EP256MC206	1024	256	32	5	+	1	0	1	2	2		5	2	· ·	10	5/4	165	163	55	04	QFN
dsPIC33EP512MC206	1024	512	48																		
dsPIC33EP32MC502	512	32	4																		
dsPIC33EP64MC502	1024	64	8																		SPDIP, SOIC,
dsPIC33EP128MC502	1024	128	16	5	4	4	6	1	2	2	1	3	2	1	6	2/3(1)	Yes	Yes	21	28	SOIC, SSOP ⁽⁵⁾ ,
dsPIC33EP256MC502	1024	256	32																		QFN-S
dsPIC33EP512MC502	1024	512	48																		
dsPIC33EP32MC503	512	32	4	5	4	4	6	1	2	2	1	3	2	1	8	3/4	Yes	Yes	25	36	VTLA
dsPIC33EP64MC503	1024	64	8	~					_	_			_		Ĵ	<i></i>					

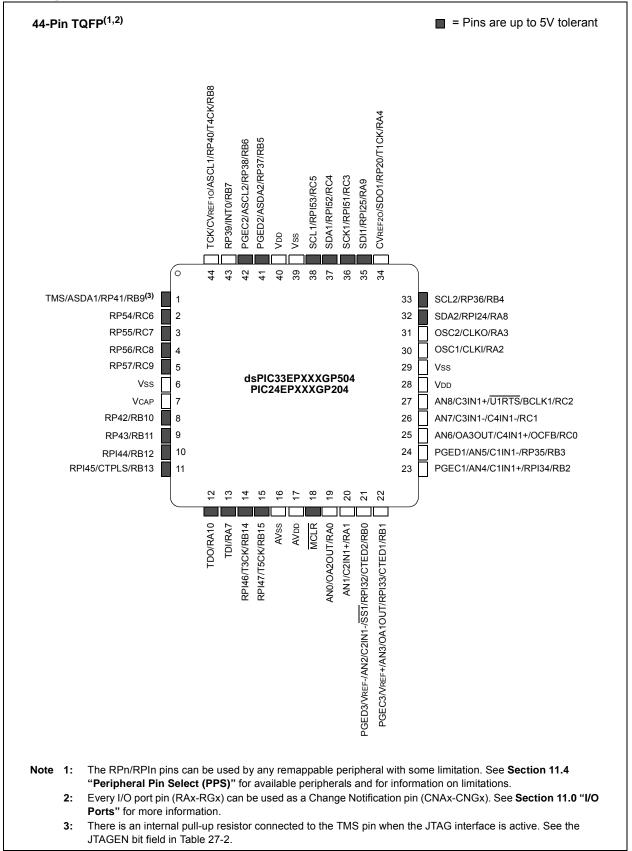
Note 1: On 28-pin devices, Comparator 4 does not have external connections. Refer to Section 25.0 "Op Amp/Comparator Module" for details. 2: Only SPI2 is remappable.

3: INTO is not remappable.

4: Only the PWM Faults are remappable.

5: The SSOP and VTLA packages are not available for devices with 512 Kbytes of memory.

Pin Diagrams (Continued)



4.2 Data Address Space

The dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/ 50X and PIC24EPXXXGP/MC20X CPU has a separate 16-bit-wide data memory space. The Data Space is accessed using separate Address Generation Units (AGUs) for read and write operations. The data memory maps, which are presented by device family and memory size, are shown in Figure 4-7 through Figure 4-16.

All Effective Addresses (EAs) in the data memory space are 16 bits wide and point to bytes within the Data Space. This arrangement gives a base Data Space address range of 64 Kbytes (32K words).

The base Data Space address is used in conjunction with a Read or Write Page register (DSRPAG or DSWPAG) to form an Extended Data Space, which has a total address range of 16 Mbytes.

dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X and PIC24EPXXXGP/MC20X devices implement up to 52 Kbytes of data memory (4 Kbytes of data memory for Special Function Registers and up to 48 Kbytes of data memory for RAM). If an EA points to a location outside of this area, an all-zero word or byte is returned.

4.2.1 DATA SPACE WIDTH

The data memory space is organized in byteaddressable, 16-bit-wide blocks. Data is aligned in data memory and registers as 16-bit words, but all Data Space EAs resolve to bytes. The Least Significant Bytes (LSBs) of each word have even addresses, while the Most Significant Bytes (MSBs) have odd addresses.

4.2.2 DATA MEMORY ORGANIZATION AND ALIGNMENT

To maintain backward compatibility with PIC[®] MCU devices and improve Data Space memory usage efficiency, the dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X and PIC24EPXXXGP/ MC20X instruction set supports both word and byte operations. As a consequence of byte accessibility, all Effective Address calculations are internally scaled to step through word-aligned memory. For example, the core recognizes that Post-Modified Register Indirect Addressing mode [Ws++] results in a value of Ws + 1 for byte operations and Ws + 2 for word operations.

A data byte read, reads the complete word that contains the byte, using the LSb of any EA to determine which byte to select. The selected byte is placed onto the LSB of the data path. That is, data memory and registers are organized as two parallel, byte-wide entities with shared (word) address decode but separate write lines. Data byte writes only write to the corresponding side of the array or register that matches the byte address. All word accesses must be aligned to an even address. Misaligned word data fetches are not supported, so care must be taken when mixing byte and word operations, or translating from 8-bit MCU code. If a misaligned read or write is attempted, an address error trap is generated. If the error occurred on a read, the instruction underway is completed. If the error occurred on a write, the instruction is executed but the write does not occur. In either case, a trap is then executed, allowing the system and/or user application to examine the machine state prior to execution of the address Fault.

All byte loads into any W register are loaded into the LSB. The MSB is not modified.

A Sign-Extend (SE) instruction is provided to allow user applications to translate 8-bit signed data to 16-bit signed values. Alternatively, for 16-bit unsigned data, user applications can clear the MSB of any W register by executing a Zero-Extend (ZE) instruction on the appropriate address.

4.2.3 SFR SPACE

The first 4 Kbytes of the Near Data Space, from 0x0000 to 0x0FFF, is primarily occupied by Special Function Registers (SFRs). These are used by the dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X and PIC24EPXXXGP/MC20X core and peripheral modules for controlling the operation of the device.

SFRs are distributed among the modules that they control and are generally grouped together by module. Much of the SFR space contains unused addresses; these are read as '0'.

Note: The actual set of peripheral features and interrupts varies by the device. Refer to the corresponding device tables and pinout diagrams for device-specific information.

4.2.4 NEAR DATA SPACE

The 8-Kbyte area, between 0x0000 and 0x1FFF, is referred to as the Near Data Space. Locations in this space are directly addressable through a 13-bit absolute address field within all memory direct instructions. Additionally, the whole Data Space is addressable using MOV instructions, which support Memory Direct Addressing mode with a 16-bit address field, or by using Indirect Addressing mode using a working register as an Address Pointer.

																		All
File Name	Addr.	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Resets
PTGCST	0AC0	PTGEN	TGEN – PTGSIDL PTGTOGL – PTGSWT PTGSSEN PTGIVIS PTGSTRT PTGWTO – – – – PTGITM<1:0>								0000							
PTGCON	0AC2	F	PTGCLK<2:0> PTGDIV<4:0> PTGPWD<3:0> — PTGWDT<2								TGWDT<2:	0>	0000					
PTGBTE	0AC4		ADC	TS<4:1>		IC4TSS	IC3TSS	IC2TSS	IC1TSS	OC4CS	OC3CS	OC2CS	OC1CS	OC4TSS	OC3TSS	OC2TSS	OC1TSS	0000
PTGHOLD	0AC6								PTGHOLD	<15:0>								0000
PTGT0LIM	0AC8								PTGT0LIM	<15:0>								0000
PTGT1LIM	0ACA								PTGT1LIM	<15:0>								0000
PTGSDLIM	0ACC								PTGSDLIN	l<15:0>								0000
PTGC0LIM	0ACE	PTGC0LIM<15:0>									0000							
PTGC1LIM	0AD0	PTGC1LIM<15:0>									0000							
PTGADJ	0AD2								PTGADJ<	:15:0>								0000
PTGL0	0AD4								PTGL0<	15:0>								0000
PTGQPTR	0AD6	—	—	—	—	_	—	—	_	—	—	-		P	TGQPTR<4	4:0>		0000
PTGQUE0	0AD8				STEP	1<7:0>							STEPO)<7:0>				0000
PTGQUE1	0ADA				STEP	'3<7:0>							STEP2	2<7:0>				0000
PTGQUE2	0ADC				STEP	25<7:0>				STEP4<7:0>							0000	
PTGQUE3	0ADE	STEP7<7:0>							STEP6<7:0>							0000		
PTGQUE4	0AE0	STEP9<7:0>								STEP8<7:0>							0000	
PTGQUE5	0AE2	STEP11<7:0>								STEP10<7:0>						0000		
PTGQUE6	0AE4	STEP13<7:0>							STEP12<7:0>						0000			
PTGQUE7	0AE6	STEP15<7:0> STEP14<7:0>								0000								

Legend: — = unimplemented, read as '0'. Reset values are shown in hexadecimal.

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TABLE 4-41: PMD REGISTER MAP FOR dsPIC33EPXXXMC20X DEVICES ONLY

File Name	Addr.	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	All Resets
PMD1	0760	T5MD	T4MD	T3MD	T2MD	T1MD	QEI1MD	PWMMD	—	I2C1MD	U2MD	U1MD	SPI2MD	SPI1MD	_	_	AD1MD	0000
PMD2	0762	_	_	_	_	IC4MD	IC3MD	IC2MD	IC1MD	_	_	_	_	OC4MD	OC3MD	OC2MD	OC1MD	0000
PMD3	0764	_	_	—	—	_	CMPMD	_	_	CRCMD	_	—	_	—	—	I2C2MD	_	0000
PMD4	0766	_		_	_	_	_	_	_	_	_	_	_	REFOMD	CTMUMD	_	_	0000
PMD6	076A	_		_	_	_	PWM3MD	PWM2MD	PWM1MD	_	_	_	_	_	_	_	_	0000
													DMA0MD					
PMD7	076C												DMA1MD	PTGMD				0000
PIVID7	0760	_	_	_	_	_	_	_	_	_	_	_	DMA2MD	FIGMD	_	_	_	0000
													DMA3MD					

Legend: — = unimplemented, read as '0'. Reset values are shown in hexadecimal.

4.8.1 DATA ACCESS FROM PROGRAM MEMORY USING TABLE INSTRUCTIONS

The TBLRDL and TBLWTL instructions offer a direct method of reading or writing the lower word of any address within the Program Space without going through Data Space. The TBLRDH and TBLWTH instructions are the only method to read or write the upper 8 bits of a Program Space word as data.

The PC is incremented by two for each successive 24-bit program word. This allows program memory addresses to directly map to Data Space addresses. Program memory can thus be regarded as two 16-bit-wide word address spaces, residing side by side, each with the same address range. TBLRDL and TBLWTL access the space that contains the least significant data word. TBLRDH and TBLWTH access the space that contains the upper data byte.

Two table instructions are provided to move byte or word-sized (16-bit) data to and from Program Space. Both function as either byte or word operations.

- TBLRDL (Table Read Low):
 - In Word mode, this instruction maps the lower word of the Program Space location (P<15:0>) to a data address (D<15:0>)

- In Byte mode, either the upper or lower byte of the lower program word is mapped to the lower byte of a data address. The upper byte is selected when Byte Select is '1'; the lower byte is selected when it is '0'.
- TBLRDH (Table Read High):
 - In Word mode, this instruction maps the entire upper word of a program address (P<23:16>) to a data address. The 'phantom' byte (D<15:8>) is always '0'.
 - In Byte mode, this instruction maps the upper or lower byte of the program word to D<7:0> of the data address in the TBLRDL instruction. The data is always '0' when the upper 'phantom' byte is selected (Byte Select = 1).

In a similar fashion, two table instructions, TBLWTH and TBLWTL, are used to write individual bytes or words to a Program Space address. The details of their operation are explained in **Section 5.0 "Flash Program Memory"**.

For all table operations, the area of program memory space to be accessed is determined by the Table Page register (TBLPAG). TBLPAG covers the entire program memory space of the device, including user application and configuration spaces. When TBLPAG<7> = 0, the table page is located in the user memory space. When TBLPAG<7> = 1, the page is located in configuration space.

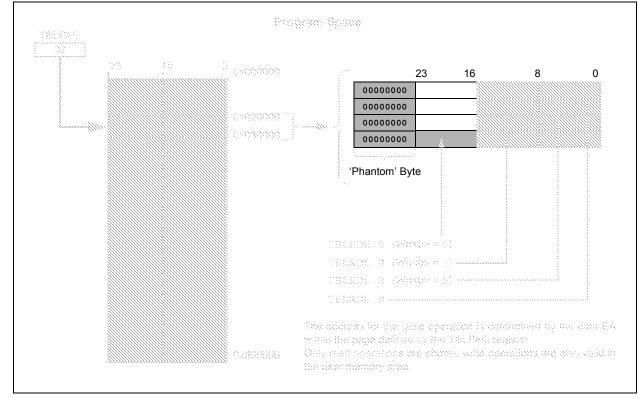


FIGURE 4-23: ACCESSING PROGRAM MEMORY WITH TABLE INSTRUCTIONS

-n = Value at POR '1' = Bit is set				'0' = Bit is cleared x = Bit is unknown					
R = Readable bit W = Writable bit				U = Unimplemented bit, read as '0'					
Legend:									
bit 7							bit C		
			NVMAD)R<23:16>					
R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x		
bit 15							bit 8		
_	—	—	—	—	_	—	—		
U-0	U-0	U-0	U-0	U-0	U-0	U-0	U-0		

bit 15-8 Unimplemented: Read as '0'

bit 7-0 **NVMADR<23:16>:** Nonvolatile Memory Write Address High bits Selects the upper 8 bits of the location to program or erase in program Flash memory. This register may be read or written by the user application.

REGISTER 5-3: NVMADRL: NONVOLATILE MEMORY ADDRESS REGISTER LOW

R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x		
			NVMA	DR<15:8>					
bit 15							bit 8		
R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x		
			NVMA	DR<7:0>					
bit 7							bit 0		
Legend:									
R = Readable bit W = Writable bit			it	U = Unimplemented bit, read as '0'					
-n = Value at POR (1' = Bit is set				'0' = Bit is cleared x = Bit is unknown					

bit 15-0 NVMADR<15:0>: Nonvolatile Memory Write Address Low bits

Selects the lower 16 bits of the location to program or erase in program Flash memory. This register may be read or written by the user application.

REGISTER 5-4: NVMKEY: NONVOLATILE MEMORY KEY

U-0	U-0	U-0	U-0	U-0	U-0	U-0	U-0
—	—	—	—	—	—	—	—
bit 15							bit 8
W-0	W-0	W-0	W-0	W-0	W-0	W-0	W-0
			NVMK	EY<7:0>			
bit 7							bit 0
Legend:							
R = Readable I	bit	W = Writable	bit	U = Unimple	mented bit, rea	d as '0'	
-n = Value at P	OR	'1' = Bit is set		'0' = Bit is cle	eared	x = Bit is unkr	nown

bit 15-8 Unimplemented: Read as '0'

bit 7-0 **NVMKEY<7:0>:** Key Register (write-only) bits

dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X AND PIC24EPXXXGP/MC20X

R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
			IC2R<6:0>			
·						bit 8
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
			IC1R<6:0>			
						bit C
e bit	W = Writable b	it	U = Unimplem	nented bit, rea	d as '0'	
-n = Value at POR '1' = Bit is set				ared	x = Bit is unkr	nown
•			nbers)			
		1				
Unimplemer	nted: Read as '0					
(see Table 11 1111001 = I	I-2 for input pin's nput tied to RPI1	election num 21		onding RPn Pi	n bits	
	e bit POR Unimplemen IC2R<6:0>: / (see Table 11 1111001 = I 0000001 = I 0000000 = I Unimplemen IC1R<6:0>: / (see Table 11 1111001 = I	e bit W = Writable b POR '1' = Bit is set Unimplemented: Read as '0 IC2R<6:0>: Assign Input Cap (see Table 11-2 for input pin s 1111001 = Input tied to RPI1 0000001 = Input tied to CMP 0000000 = Input tied to Vss Unimplemented: Read as '0 IC1R<6:0>: Assign Input Cap (see Table 11-2 for input pin s	e bit W = Writable bit POR '1' = Bit is set Unimplemented: Read as '0' IC2R<6:0>: Assign Input Capture 2 (IC2) (see Table 11-2 for input pin selection num 1111001 = Input tied to RPI121	R/W-0 R/W-0 R/W-0 R/W-0 IC1R<6:0> IC1R<6:0> e bit W = Writable bit U = Unimplem POR '1' = Bit is set '0' = Bit is clear Unimplemented: Read as '0' IC2R<6:0>: Assign Input Capture 2 (IC2) to the Correspond (see Table 11-2 for input pin selection numbers) 1111001 = Input tied to RPI121 . . 0000001 = Input tied to CMP1 0000000 = Input tied to Vss Unimplemented: Read as '0' IC1R<6:0>: Assign Input Capture 1 (IC1) to the Correspond (see Table 11-2 for input pin selection numbers) 1111001 = Input tied to RPI121 .	R/W-0 R/W-0 R/W-0 R/W-0 IC1R<6:0> e bit W = Writable bit U = Unimplemented bit, real POR '1' = Bit is set '0' = Bit is cleared Unimplemented: Read as '0' IC2R<6:0>: Assign Input Capture 2 (IC2) to the Corresponding RPn Pi (see Table 11-2 for input pin selection numbers) 1111001 = Input tied to RPI121 . . . 0000001 = Input tied to CMP1 0000000 = Input tied to Vss Unimplemented: Read as '0' IC1R<6:0>: Assign Input Capture 1 (IC1) to the Corresponding RPn Pi (see Table 11-2 for input pin selection numbers) 1111001 = Input tied to RPI121 .	R/W-0 R/W-0 R/W-0 R/W-0 R/W-0 IC1R<6:0> e bit W = Writable bit U = Unimplemented bit, read as '0' POR '1' = Bit is set '0' = Bit is cleared x = Bit is unkr Unimplemented: Read as '0' IC2R<6:0>: Assign Input Capture 2 (IC2) to the Corresponding RPn Pin bits (see Table 11-2 for input pin selection numbers) 1111001 = Input tied to RPI121 <p< td=""></p<>

REGISTER 11-4: RPINR7: PERIPHERAL PIN SELECT INPUT REGISTER 7

REGISTER 17-2: QEI1IOC: QEI1 I/O CONTROL REGISTER (CONTINUED)

- bit 2 INDEX: Status of INDXx Input Pin After Polarity Control
 - 1 = Pin is at logic '1'
 - 0 = Pin is at logic '0'
- bit 1 QEB: Status of QEBx Input Pin After Polarity Control And SWPAB Pin Swapping 1 = Pin is at logic '1' 0 = Pin is at logic '0'
- bit 0 **QEA:** Status of QEAx Input Pin After Polarity Control And SWPAB Pin Swapping 1 = Pin is at logic '1'
 - 0 = Pin is at logic '0'

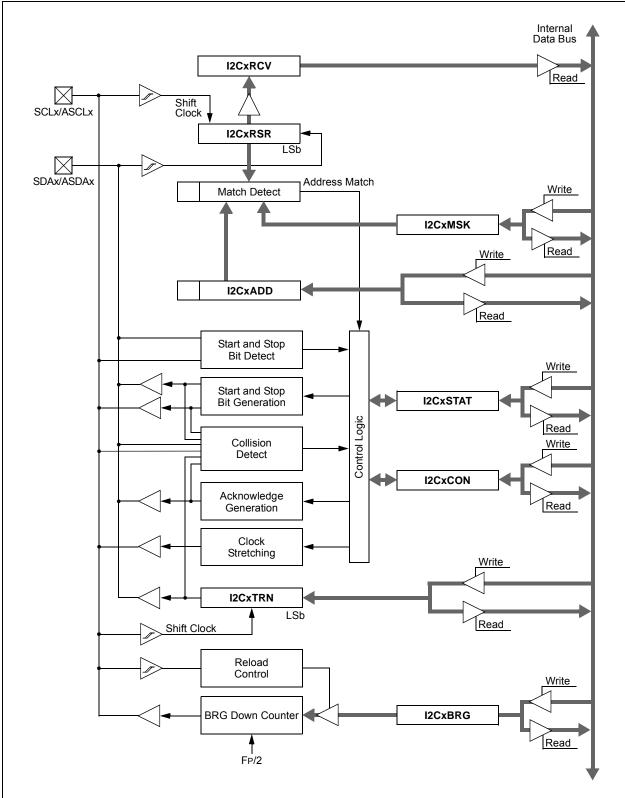


FIGURE 19-1: I2Cx BLOCK DIAGRAM (X = 1 OR 2)

	D MALO								
	1	U-0	0-0	0-0	0-0	U-0			
DMABS1	DMABS0		—	—	—	—			
						bit 8			
					DAMO				
0-0	0-0		1	-	-	R/W-0			
—	—	FSA4	FSA3	FSA2	FSA1	FSA0			
						bit 0			
bit	W = Writable b	U = Unimplen	nented bit, rea	d as '0'					
POR	'1' = Bit is set		'0' = Bit is clea	ared	x = Bit is unkn	own			
110 = 32 buffers in RAM 101 = 24 buffers in RAM 100 = 16 buffers in RAM 011 = 12 buffers in RAM 010 = 8 buffers in RAM 001 = 6 buffers in RAM 000 = 4 buffers in RAM									
-									
11111 = Rea	d Buffer RB31	with Buffer b	its						
	DMABS<2:0 111 = Reserv 110 = 32 buff 101 = 24 buff 100 = 16 buff 011 = 12 buff 010 = 8 buffe 001 = 6 buffe 000 = 4 buffe Unimplement FSA<4:0>: F 11111 = Rea	DMABS1 DMABS0 U-0 U-0 — — bit W = Writable to the second seco	DMABS1 DMABS0 — U-0 U-0 R/W-0 — — FSA4 bit W = Writable bit POR '1' = Bit is set DMABS 2:0>: DMA Buffer Size bits 111 = Reserved 110 = 32 buffers in RAM 101 = 24 buffers in RAM 100 = 16 buffers in RAM 011 = 12 buffers in RAM 010 = 8 buffers in RAM 010 = 6 buffers in RAM 000 = 4 buffers in RAM 000 = 4 buffers in RAM 000 = 4 buffers in RAM 011 = 6 buffers in RAM 001 = 6 buffers in RAM 001 = 8 buffers in RAM 001 = 8 buffers in RAM 000 = 4 buffers in RAM 111 = Read Buffer RB31	DMABS1 DMABS0 — — U-0 U-0 R/W-0 R/W-0 — — FSA4 FSA3 bit W = Writable bit U = Unimplen POR '1' = Bit is set '0' = Bit is clear DMABS -: :0' = Bit is clear DMABS :0' = Bit is clear :0' = Bit is clear DMABS :0' = Bit is clear :0' = Bit is clear DMABS :0' = Bit is clear :0' = Bit is clear DMABS :0' = Bit is clear :0' = Bit is clear DMABS :0' = Bit is clear :0' = Bit is clear DMABS :0' = Bit is clear :0' = Bit is clear DMABS :0' = Bit is clear :0' = Bit is clear DMABS :0' = Bit is clear :0' = Bit is clear DMABS : DMA Buffers in RAM :0' = Bit is clear 100 = 16 buffers in RAM :01 = 12 buffers in RAM :01 = 8 buffers in RAM 001 = 6 buffers in RAM :00 = 4 buffers in RAM :00 = 4 buffers in RAM 000 = 4 buffers in RAM :0' = FIFO Area Starts with Buffer bits :1111 = Read Buffer RB31	DMABS1 DMABS0 — <th< td=""><td>DMABS1 DMABS0 U-0 U-0 R/W-0 R/W-0 R/W-0 R/W-0 FSA4 FSA3 FSA2 FSA1 bit W = Writable bit U = Unimplemented bit, read as '0' POR '1' = Bit is set '0' = Bit is cleared x = Bit is unkn DMABS 2:0>: DMA Buffer Size bits 111 = Reserved 10 = 32 buffers in RAM 101 = 24 buffers in RAM 100 = 16 buffers in RAM 011 = 12 buffers in RAM 011 = 12 buffers in RAM 010 = 8 buffers in RAM 001 = 6 buffers in RAM 001 = 6 buffers in RAM 000 = 4 buffers in RAM Unimplemented: Read as '0' FSA FSA FSA FSA FSA U111 = Read Buffer RB31 East with Buffer bits 1111 = Read Buffer RB31</td></th<>	DMABS1 DMABS0 U-0 U-0 R/W-0 R/W-0 R/W-0 R/W-0 FSA4 FSA3 FSA2 FSA1 bit W = Writable bit U = Unimplemented bit, read as '0' POR '1' = Bit is set '0' = Bit is cleared x = Bit is unkn DMABS 2:0>: DMA Buffer Size bits 111 = Reserved 10 = 32 buffers in RAM 101 = 24 buffers in RAM 100 = 16 buffers in RAM 011 = 12 buffers in RAM 011 = 12 buffers in RAM 010 = 8 buffers in RAM 001 = 6 buffers in RAM 001 = 6 buffers in RAM 000 = 4 buffers in RAM Unimplemented: Read as '0' FSA FSA FSA FSA FSA U111 = Read Buffer RB31 East with Buffer bits 1111 = Read Buffer RB31			

REGISTER 21-4: CxFCTRL: ECANx FIFO CONTROL REGISTER

dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X AND PIC24EPXXXGP/MC20X

R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
ADCTS4	ADCTS3	ADCTS2	ADCTS1	IC4TSS	IC3TSS	IC2TSS	IC1TSS
bit 15							bit 8
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
OC4CS		OC2CS	OC1CS	OC4TSS	OC3TSS	OC2TSS	OC1TSS
bit 7							bit (
Legend:							
R = Reada	ble bit	W = Writable	bit	U = Unimplei	mented bit, read	l as '0'	
-n = Value	at POR	'1' = Bit is set		'0' = Bit is cle		x = Bit is unkr	nown
bit 15	ADCTS4: Sa	mple Trigger P	TGO15 for AE	OC bit			
	1 = Generate	es Trigger wher	the broadcas	t command is	executed		
	0 = Does not	generate Trigg	er when the b	roadcast com	mand is execute	ed	
bit 14		mple Trigger P					
		es Trigger wher				al	
bit 13					mand is execute	a	
DIE 13		mple Trigger P es Trigger wher			evecuted		
					mand is execute	ed	
bit 12		mple Trigger P					
	1 = Generate	es Trigger wher	the broadcas	t command is	executed		
					mand is execute	ed	
bit 11	-	ger/Synchroniz					
					ast command is broadcast con		ited
bit 10	IC3TSS: Trig	ger/Synchroniz	ation Source f	for IC3 bit			
					ast command is broadcast con		ited
bit 9	IC2TSS: Trig	ger/Synchroniz	ation Source f	for IC2 bit			
					ast command is broadcast con		ited
bit 8		ger/Synchroniz					
					ast command is broadcast con		ited
bit 7		ck Source for C	-				
		es clock pulse v generate clock			d is executed command is exe	cuted	
bit 6		ck Source for C	-				
		es clock pulse v aenerate clock			d is executed command is exe	cuted	
bit 5		ck Source for C	-				
	1 = Generate	es clock pulse v	when the broad		d is executed command is exe	cuted	
	This register is rea PTGSTRT = 1).	-					and
	This register is on	lv used with the	PTGCTRI. OI	PTION = 1111	Step command	L	
		.,			c.op commune	•	

REGISTER 24-3: PTGBTE: PTG BROADCAST TRIGGER ENABLE REGISTER^(1,2)

24.4 Step Commands and Format

TABLE 24-1: PTG STEP COMMAND FORMAT

Step Command Byte:		
	STEPx<7:0>	
CMD<3:0>		OPTION<3:0>
bit 7	bit 4 bit 3	bit 0

bit 7-4	CMD<3:0>	Step Command	Command Description
	0000	PTGCTRL	Execute control command as described by OPTION<3:0>.
	0001	PTGADD	Add contents of PTGADJ register to target register as described by OPTION<3:0>.
		PTGCOPY	Copy contents of PTGHOLD register to target register as described by OPTION<3:0>.
	001x	PTGSTRB	Copy the value contained in CMD<0>:OPTION<3:0> to the CH0SA<4:0> bits (AD1CHS0<4:0>).
	0100	PTGWHI	Wait for a low-to-high edge input from the selected PTG trigger input as described by OPTION<3:0>.
	0101	PTGWLO	Wait for a high-to-low edge input from the selected PTG trigger input as described by OPTION<3:0>.
	0110	Reserved	Reserved.
	0111	PTGIRQ	Generate individual interrupt request as described by OPTION3<:0>.
	100x	PTGTRIG	Generate individual trigger output as described by < <cmd<0>:OPTION<3:0>>.</cmd<0>
	101x	PTGJMP	Copy the value indicated in < <cmd<0>:OPTION<3:0>> to the Queue Pointer (PTGQPTR) and jump to that Step queue.</cmd<0>
	110x	PTGJMPC0	PTGC0 = PTGC0LIM: Increment the Queue Pointer (PTGQPTR).
			$PTGC0 \neq PTGC0LIM$: Increment Counter 0 (PTGC0) and copy the value indicated in < <cmd<0>:OPTION<3:0>> to the Queue Pointer (PTGQPTR), and jump to that Step queue</cmd<0>
	111x	PTGJMPC1	PTGC1 = PTGC1LIM: Increment the Queue Pointer (PTGQPTR).
			$PTGC1 \neq PTGC1LIM$: Increment Counter 1 (PTGC1) and copy the value indicated in < <cmd<0>:OPTION<3:0>> to the Queue Pointer (PTGQPTR), and jump to that Step queue.</cmd<0>

Note 1: All reserved commands or options will execute but have no effect (i.e., execute as a NOP instruction).

2: Refer to Table 24-2 for the trigger output descriptions.

3: This feature is only available on dsPIC33EPXXXMC20X/50X and PIC24EPXXXMC20X devices.

Base Instr #	Assembly Mnemonic		Assembly Syntax	Description	# of Words	# of Cycles ⁽²⁾	Status Flags Affected
25	DAW	DAW	Wn	Wn = decimal adjust Wn	1	1	С
26	DEC	DEC	f	f = f - 1	1	1	C,DC,N,OV,Z
		DEC	f,WREG	WREG = f – 1	1	1	C,DC,N,OV,Z
		DEC	Ws,Wd	Wd = Ws - 1	1	1	C,DC,N,OV,Z
27	DEC2	DEC2	f	f = f - 2	1	1	C,DC,N,OV,Z
		DEC2	f,WREG	WREG = f – 2	1	1	C,DC,N,OV,Z
		DEC2	Ws,Wd	Wd = Ws - 2	1	1	C,DC,N,OV,Z
28	DISI	DISI	#lit14	Disable Interrupts for k instruction cycles	1	1	None
29	DIV	DIV.S	Wm,Wn	Signed 16/16-bit Integer Divide	1	18	N,Z,C,OV
		DIV.SD	Wm,Wn	Signed 32/16-bit Integer Divide	1	18	N,Z,C,OV
		DIV.U	Wm,Wn	Unsigned 16/16-bit Integer Divide	1	18	N,Z,C,OV
		DIV.UD	Wm,Wn	Unsigned 32/16-bit Integer Divide	1	18	N,Z,C,OV
30	DIVF	DIVF	Wm , Wn ⁽¹⁾	Signed 16/16-bit Fractional Divide	1	18	N,Z,C,OV
31	DO	DO	#lit15,Expr ⁽¹⁾	Do code to PC + Expr, lit15 + 1 times	2	2	None
		DO	Wn, Expr(1)	Do code to PC + Expr, (Wn) + 1 times	2	2	None
32	ED	ED	Wm*Wm,Acc,Wx,Wy,Wxd ⁽¹⁾	Euclidean Distance (no accumulate)	1	1	OA,OB,OAB, SA,SB,SAB
33	EDAC	EDAC	Wm*Wm,Acc,Wx,Wy,Wxd ⁽¹⁾	Euclidean Distance	1	1	OA,OB,OAB, SA,SB,SAB
34	EXCH	EXCH	Wns,Wnd	Swap Wns with Wnd	1	1	None
35	FBCL	FBCL	Ws,Wnd	Find Bit Change from Left (MSb) Side	1	1	С
36	FF1L	FF1L	Ws,Wnd	Find First One from Left (MSb) Side	1	1	С
37	FF1R	FF1R	Ws,Wnd	Find First One from Right (LSb) Side	1	1	С
38	GOTO	GOTO	Expr	Go to address	2	4	None
		GOTO	Wn	Go to indirect	1	4	None
		GOTO.L	Wn	Go to indirect (long address)	1	4	None
39	INC	INC	f	f = f + 1	1	1	C,DC,N,OV,Z
		INC	f,WREG	WREG = f + 1	1	1	C,DC,N,OV,Z
		INC	Ws,Wd	Wd = Ws + 1	1	1	C,DC,N,OV,Z
40	INC2	INC2	f	f = f + 2	1	1	C,DC,N,OV,Z
		INC2	f,WREG	WREG = f + 2	1	1	C,DC,N,OV,Z
		INC2	Ws,Wd	Wd = Ws + 2	1	1	C,DC,N,OV,Z
41	IOR	IOR	f	f = f .IOR. WREG	1	1	N,Z
		IOR	f,WREG	WREG = f .IOR. WREG	1	1	N,Z
		IOR	#lit10,Wn	Wd = lit10 .IOR. Wd	1	1	N,Z
		IOR	Wb,Ws,Wd	Wd = Wb .IOR. Ws	1	1	N,Z
		IOR	Wb,#lit5,Wd	Wd = Wb .IOR. lit5	1	1	N,Z
42	LAC	LAC	Wso,#Slit4,Acc	Load Accumulator	1	1	OA,OB,OAB, SA,SB,SAB
43	LNK	LNK	#lit14	Link Frame Pointer	1	1	SFA
44	LSR	LSR	f	f = Logical Right Shift f	1	1	C,N,OV,Z
		LSR	f,WREG	WREG = Logical Right Shift f	1	1	C,N,OV,Z
		LSR	Ws,Wd	Wd = Logical Right Shift Ws	1	1	C,N,OV,Z
		LSR	Wb,Wns,Wnd	Wnd = Logical Right Shift Wb by Wns	1	1	N,Z
		LSR	Wb,#lit5,Wnd	Wnd = Logical Right Shift Wb by lit5	1	1	N,Z
45	MAC	MAC	Wm*Wn,Acc,Wx,Wxd,Wy,Wyd,AWB ⁽¹⁾	Multiply and Accumulate	1	1	OA,OB,OAB, SA,SB,SAB
		MAC	Wm*Wm,Acc,Wx,Wxd,Wy,Wyd ⁽¹⁾	Square and Accumulate	1	1	OA,OB,OAB, SA,SB,SAB

TABLE 28-2: INSTRUCTION SET OVERVIEW (CONTINUED)

Note 1: These instructions are available in dsPIC33EPXXXMC20X/50X and PIC24EPXXXMC20X devices only.

2: Read and Read-Modify-Write (e.g., bit operations and logical operations) on non-CPU SFRs incur an additional instruction cycle.

TABLE 30-18: PLL CLOCK TIMING SPECIFICATIONS

АС СНА	RACTERI	STICS	$\begin{array}{l} \mbox{Standard Operating Conditions: 3.0V to 3.6V} \\ \mbox{(unless otherwise stated)} \\ \mbox{Operating temperature} & -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for Industrial} \\ & -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for Extended} \end{array}$				
Param No.	Symbol	Characteristic	Min. Typ. ⁽¹⁾ Max. Units Conditions				
OS50	Fplli	PLL Voltage Controlled Oscillator (VCO) Input Frequency Range	0.8	_	8.0	MHz	ECPLL, XTPLL modes
OS51	Fvco	On-Chip VCO System Frequency	120	—	340	MHz	
OS52	52 TLOCK PLL Start-up Time (Lock Time)		0.9	1.5	3.1	ms	
OS53				0.5	3	%	

Note 1: Data in "Typical" column is at 3.3V, +25°C unless otherwise stated. Parameters are for design guidance only and are not tested.

2: This jitter specification is based on clock cycle-by-clock cycle measurements. To get the effective jitter for individual time bases, or communication clocks used by the application, use the following formula:

$$Effective Jitter = \frac{DCLK}{\sqrt{\frac{FOSC}{Time Base or Communication Clock}}}$$

For example, if Fosc = 120 MHz and the SPIx bit rate = 10 MHz, the effective jitter is as follows:

Effective Jitter =
$$\frac{DCLK}{\sqrt{\frac{120}{10}}} = \frac{DCLK}{\sqrt{12}} = \frac{DCLK}{3.464}$$

TABLE 30-19: INTERNAL FRC ACCURACY

AC CHA	RACTERISTICS	$\begin{array}{llllllllllllllllllllllllllllllllllll$						
Param No. Characteristic		Min.	Тур.	Max.	Units	Conditio	ons	
Internal	FRC Accuracy @ FRC Fre	equency =	: 7.37 MHz	<u>,(1)</u>				
F20a	FRC	-1.5	0.5	+1.5	%	$-40^{\circ}C \le TA \le -10^{\circ}C$	VDD = 3.0-3.6V	
		-1	0.5	+1	%	$-10^{\circ}C \le TA \le +85^{\circ}C \qquad VDD = 3.0-3.6^{\circ}$		
F20b	FRC -2 1 +2 % +85°C ≤ TA ≤ +125°C VDD =				VDD = 3.0-3.6V			

Note 1: Frequency is calibrated at +25°C and 3.3V. TUNx bits can be used to compensate for temperature drift.

TABLE 30-20: INTERNAL LPRC ACCURACY

AC CH	ARACTERISTICS	$\begin{array}{ll} \mbox{Standard Operating Conditions: 3.0V to 3.6V (unless otherwise stated)} \\ \mbox{Operating temperature} & -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for Industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for Extended} \end{array}$						
Param No. Characteristic		Min.	Тур.	Max.	Units	Conditions		
LPRC (@ 32.768 kHz ⁽¹⁾							
F21a	LPRC	-30	—	+30	%	$-40^{\circ}C \le TA \le -10^{\circ}C$	VDD = 3.0-3.6V	
		-20	_	+20	%	$-10^{\circ}C \leq TA \leq +85^{\circ}C$	VDD = 3.0-3.6V	
F21b LPRC		-30	_	+30	%	$+85^{\circ}C \leq TA \leq +125^{\circ}C$	VDD = 3.0-3.6V	

Note 1: The change of LPRC frequency as VDD changes.

	RACTERI	STICS		Standard Operating Conditions: 3.0V to 3.6V(unless otherwise stated)Operating temperature $-40^{\circ}C \le TA \le +85^{\circ}C$ for Industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for Extended				
Param. No.	Symbol	Characte	Min.	Max.	Units	Conditions		
IS10	TLO:SCL	Clock Low Time	100 kHz mode	4.7	_	μS		
			400 kHz mode	1.3	—	μS		
			1 MHz mode ⁽¹⁾	0.5	—	μS		
IS11	THI:SCL Clock High Time		100 kHz mode	4.0	—	μS	Device must operate at a minimum of 1.5 MHz	
			400 kHz mode	0.6	—	μS	Device must operate at a minimum of 10 MHz	
			1 MHz mode ⁽¹⁾	0.5	—	μS		
IS20	TF:SCL	SDAx and SCLx	100 kHz mode		300	ns	CB is specified to be from	
		Fall Time	400 kHz mode	20 + 0.1 Св	300	ns	10 to 400 pF	
			1 MHz mode ⁽¹⁾	—	100	ns		
IS21	TR:SCL	SDAx and SCLx	100 kHz mode		1000	ns	CB is specified to be from	
		Rise Time	400 kHz mode	20 + 0.1 Св	300	ns	10 to 400 pF	
			1 MHz mode ⁽¹⁾		300	ns		
IS25	TSU:DAT	Data Input	100 kHz mode	250	—	ns		
		Setup Time	400 kHz mode	100	—	ns		
			1 MHz mode ⁽¹⁾	100	_	ns		
IS26 THD:DAT	THD:DAT	Data Input	100 kHz mode	0	—	μS		
		Hold Time	400 kHz mode	0	0.9	μS		
			1 MHz mode ⁽¹⁾	0	0.3	μS		
IS30	TSU:STA	Start Condition	100 kHz mode	4.7	—	μS	Only relevant for Repeated	
		Setup Time	400 kHz mode	0.6	—	μS	Start condition	
			1 MHz mode ⁽¹⁾	0.25	—	μS		
IS31	THD:STA	Start Condition	100 kHz mode	4.0	—	μS	After this period, the first	
		Hold Time	400 kHz mode	0.6	—	μS	clock pulse is generated	
			1 MHz mode ⁽¹⁾	0.25	—	μS		
IS33	Tsu:sto	Stop Condition	100 kHz mode	4.7	—	μS		
		Setup Time	400 kHz mode	0.6	—	μS		
			1 MHz mode ⁽¹⁾	0.6	_	μS		
IS34	THD:STO	Stop Condition	100 kHz mode	4	—	μS		
		Hold Time	400 kHz mode	0.6	—	μS		
			1 MHz mode ⁽¹⁾	0.25		μS		
IS40	TAA:SCL	Output Valid	100 kHz mode	0	3500	ns		
		From Clock	400 kHz mode	0	1000	ns		
			1 MHz mode ⁽¹⁾	0	350	ns		
IS45	TBF:SDA	Bus Free Time	100 kHz mode	4.7	—	μS	Time the bus must be free	
			400 kHz mode	1.3	—	μS	before a new transmission	
			1 MHz mode ⁽¹⁾	0.5		μs	can start	
IS50	Св	Bus Capacitive Lo	ading	—	400	pF		
S51	TPGD	Pulse Gobbler De	lay	65	390	ns	(Note 2)	

TABLE 30-50: I2Cx BUS DATA TIMING REQUIREMENTS (SLAVE MODE)

Note 1: Maximum pin capacitance = 10 pF for all I2Cx pins (for 1 MHz mode only).

2: Typical value for this parameter is 130 ns.

3: These parameters are characterized, but not tested in manufacturing.

DC CH	ARACTERIS	STICS	Standard Operating Conditions: 3.0V to 3.6V(unless otherwise stated) ⁽¹⁾ Operating temperature $-40^{\circ}C \le TA \le +85^{\circ}C$ for Industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for Extended								
Param No.	Symbol Characteristic		Min.	Тур. ⁽²⁾	Max.	Units	Conditions				
Comparator AC Characteristics											
CM10	TRESP	Response Time ⁽³⁾	—	19	—	ns	V+ input step of 100 mV V- input held at VDD/2				
CM11	Тмс2о∨	Comparator Mode Change to Output Valid	—	-	10	μs					
Compa	rator DC Ch	naracteristics									
CM30	VOFFSET	Comparator Offset Voltage	—	±10	40	mV					
CM31	VHYST	Input Hysteresis Voltage ⁽³⁾	_	30	—	mV					
CM32	Trise/ Tfall	Comparator Output Rise/ Fall Time ⁽³⁾	—	20	—	ns	1 pF load capacitance on input				
CM33	Vgain	Open-Loop Voltage Gain ⁽³⁾	—	90	—	db					
CM34	VICM	Input Common-Mode Voltage	AVss	-	AVDD	V					
Op Am	p AC Chara	cteristics									
CM20	SR	Slew Rate ⁽³⁾		9	_	V/µs	10 pF load				
CM21a	Рм	Phase Margin (Configuration A) ^(3,4)	_	55	—	Degree	G = 100V/V; 10 pF load				
CM21b	Рм	Phase Margin (Configuration B) ^(3,5)	_	40	_	Degree	G = 100V/V; 10 pF load				
CM22	Gм	Gain Margin ⁽³⁾	—	20	_	db	G = 100V/V; 10 pF load				
CM23a	Gвw	Gain Bandwidth (Configuration A) ^(3,4)	_	10	—	MHz	10 pF load				
CM23b	GBW	Gain Bandwidth (Configuration B) ^(3,5)	—	6	—	MHz	10 pF load				

TABLE 30-53: OP AMP/COMPARATOR SPECIFICATIONS

Note 1: Device is functional at VBORMIN < VDD < VDDMIN, but will have degraded performance. Device functionality is tested, but not characterized. Analog modules (ADC, op amp/comparator and comparator voltage reference) may have degraded performance. Refer to Parameter BO10 in Table 30-13 for the minimum and maximum BOR values.

- 2: Data in "Typ" column is at 3.3V, +25°C unless otherwise stated.
- 3: Parameter is characterized but not tested in manufacturing.
- 4: See Figure 25-6 for configuration information.
- 5: See Figure 25-7 for configuration information.
- 6: Resistances can vary by ±10% between op amps.

NOTES:

dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X AND PIC24EPXXXGP/MC20X

DC CHARACT	ERISTICS		(unless oth	Standard Operating Conditions: 3.0V to 3.6V (unless otherwise stated) Operating temperature $-40^{\circ}C \le TA \le +150^{\circ}C$				
Parameter No.	Typical	Мах	Units	Conditions				
Power-Down	Current (IPD)							
HDC60e	1400	2500	μA	+150°C	3.3V	Base Power-Down Current (Notes 1, 3)		
HDC61c	15	—	μA	+150°C	Watchdog Timer Current: ∆IwDT (Notes 2, 4)			

TABLE 31-4: DC CHARACTERISTICS: POWER-DOWN CURRENT (IPD)

Note 1: Base IPD is measured with all peripherals and clocks shut down. All I/Os are configured as inputs and pulled to Vss. WDT, etc., are all switched off and VREGS (RCON<8>) = 1.

2: The ∆ current is the additional current consumed when the module is enabled. This current should be added to the base IPD current.

3: These currents are measured on the device containing the most memory in this family.

4: These parameters are characterized, but are not tested in manufacturing.

TABLE 31-5: DC CHARACTERISTICS: IDLE CURRENT (IIDLE)

DC CHARAG	CTERISTICS		Standard Operating Conditions: 3.0V to 3.6V (unless otherwise stated) Operating temperature $-40^{\circ}C \le TA \le +150^{\circ}C$				
Parameter No.	Typical	Мах	Units	Conditions			
HDC44e	12	30	mA	+150°C 3.3V 40 MIPS			

TABLE 31-6: DC CHARACTERISTICS: OPERATING CURRENT (IDD)

DC CHARAC	CTERISTICS		Standard Operating Conditions: 3.0V to 3.6V (unless otherwise stated) Operating temperature $-40^{\circ}C \le TA \le +150^{\circ}C$				
Parameter No.	Typical	Max	Units	Conditions			
HDC20	9	15	mA	+150°C	3.3V	10 MIPS	
HDC22	16	25	mA	+150°C	3.3V	20 MIPS	
HDC23	30	50	mA	+150°C	3.3V	40 MIPS	

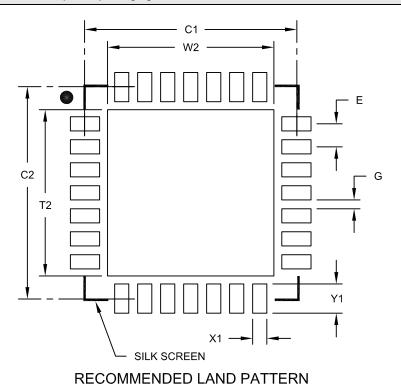
TABLE 31-7: DC CHARACTERISTICS: DOZE CURRENT (IDOZE)

DC CHARA	CTERISTICS	Standard Operating Conditions: 3.0V to 3.6V (unless otherwise stated) Operating temperature $-40^{\circ}C \le TA \le +150^{\circ}C$					
Parameter No.	Typical	Мах	Doze Ratio	Units	Conditions		
HDC72a	24	35	1:2	mA			
HDC72f ⁽¹⁾	14	—	1:64	mA	+150°C	3.3V	40 MIPS
HDC72g ⁽¹⁾	12		1:128	mA			

Note 1: Parameters with Doze ratios of 1:64 and 1:128 are characterized, but are not tested in manufacturing.

28-Lead Plastic Quad Flat, No Lead Package (MM) – 6x6x0.9 mm Body [QFN-S] with 0.40 mm Contact Length

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units					
Dimensior	Dimension Limits			MAX		
Contact Pitch	E		0.65 BSC			
Optional Center Pad Width	W2			4.70		
Optional Center Pad Length	T2			4.70		
Contact Pad Spacing	C1		6.00			
Contact Pad Spacing	C2		6.00			
Contact Pad Width (X28)	X1			0.40		
Contact Pad Length (X28) Y				0.85		
Distance Between Pads G		0.25				

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2124A